

General Description

The AOZ8045 is a 6-line device integrating EMI filtering with ESD protection for each line. It is designed to suppress unwanted EMI/RFI signals and provide electro-static discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]²™ technology for superior clamping performance and filter attenuation over the full operating display range. The AOZ8045 has been optimized for protection of color LCD displays and CCD camera lines in cellular phones and other portable consumer electronic devices.

The AOZ8045 consists of six identical circuits comprised of TVS diodes for ESD protection, and a resistor-capacitor network for EMI/RFI filtering. A series resistor value of 100Ω and a capacitance value of 9pF are used to achieve -20dB minimum attenuation from 1.0GHz to 3.0GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ±20kV (contact discharge) and ±20kV (air discharge). This exceeds IEC 61000-4-2, level 4 ESD immunity test.

The AOZ8045 comes in an RoHS compliant, 2.50mm x 1.20mm DFN package and is rated over a -40°C to +85°C ambient temperature range.

Features

- 6 lines for EMI filtering and ESD protection:
 - Exceeds IEC 61000-4-2, level 4 (ESD) immunity test
 - ±20kV (contact discharge) and ±20kV (air discharge)
- Trench Vertical Structure [TVS]²™ based technology used to achieve excellent ESD clamping and filter performance over the full operating display range
- Filter performance: -20dB attenuation from 1.0GHz to 3.0GHz
- Low operating voltage: 5.0V
- Capacitance stability over wide range of voltages and temperatures
- DFN package 2.50mm x 1.20mm
- Pb-Free device

Applications

- EMI filtering and ESD protection for data lines
- LCD displays, camera interface, I/O interface
- Portable handheld devices, cell phones, PDA phones



Electrical Schematic

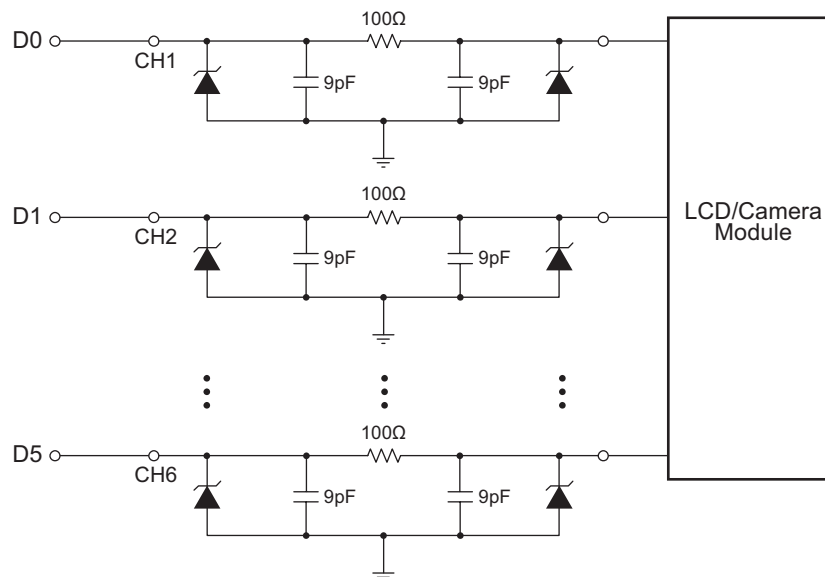


Figure 1.

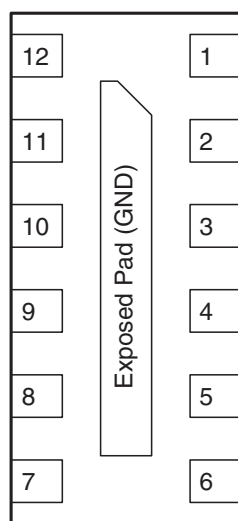
Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8045DI	-40°C to +85°C	DFN-12	RoHS Compliant Green Product

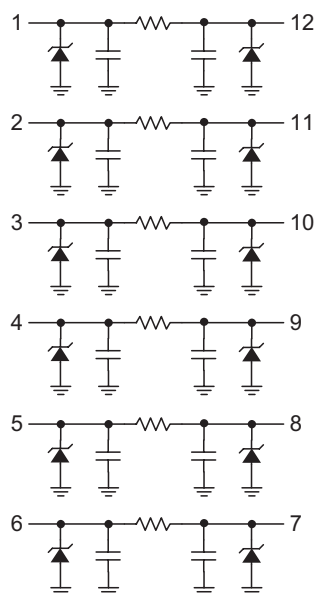


AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.
Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration



DFN-12
(Bottom View)



Top View

Pin Description

Pin Number	Pin Name	Pin Function
1, 12	CH 1	Channel 1 Connections
2, 11	CH 2	Channel 2 Connections
3, 10	CH 3	Channel 3 Connections
4, 9	CH 4	Channel 4 Connections
5, 8	CH 5	Channel 5 Connections
6, 7	CH 6	Channel 6 Connections
Exposed Pad	GND	Common Ground Connection

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±20kV
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±20kV
ESD Rating per Human Body Model ⁽²⁾	±30kV

Notes:

1. IEC 61000-4-2 discharge with C_{Discharge} = 150pF, R_{Discharge} = 330Ω.
2. Human Body Discharge per MIL-STD-883, Method 3015 C_{Discharge} = 100pF, R_{Discharge} = 1.5kΩ.

Electrical Characteristics

T_A = 25°C unless otherwise specified.

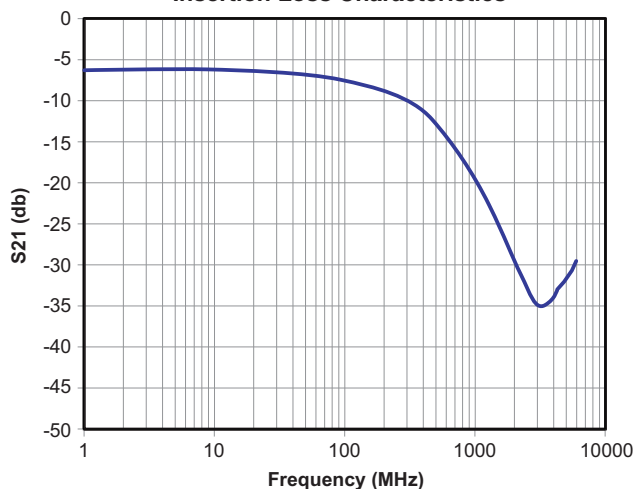
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{RWM}	Reverse Working Voltage	⁽³⁾			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA ⁽⁴⁾	6	7	8	V
I _R	Reverse Leakage Current	V _{RWM} = 3.3V			0.1	μA
V _{CL}	Signal Clamp Voltage	I _{LOAD} = 1A, positive clamp ⁽⁵⁾⁽⁸⁾			7.0	V
		I _{LOAD} = 1A, negative clamp ⁽⁵⁾⁽⁸⁾			-3.0	
		I _{LOAD} = 5A, positive clamp ⁽⁵⁾⁽⁸⁾			8.0	
		I _{LOAD} = 5A, negative clamp ⁽⁵⁾⁽⁸⁾			-8.0	
		I _{LOAD} = 12A, positive clamp ⁽⁵⁾⁽⁸⁾			10.0	
		I _{LOAD} = 12A, negative clamp ⁽⁵⁾⁽⁸⁾			-10.0	
R _{CH}	Total Series Resistance	I _R = 20mA	90	100	110	Ω
C _{CH}	Channel Capacitance	Input to Ground ⁽⁶⁾⁽⁷⁾⁽⁸⁾	8	9	10	pF
f _C	Cut-off Frequency	Measured with 50Ω source and 50Ω load termination		250		MHz
	Attenuation from 1.0GHz to 3.0GHz	V _R = 0V Measured with 50Ω source and 50Ω load termination		-20		dB

Notes:

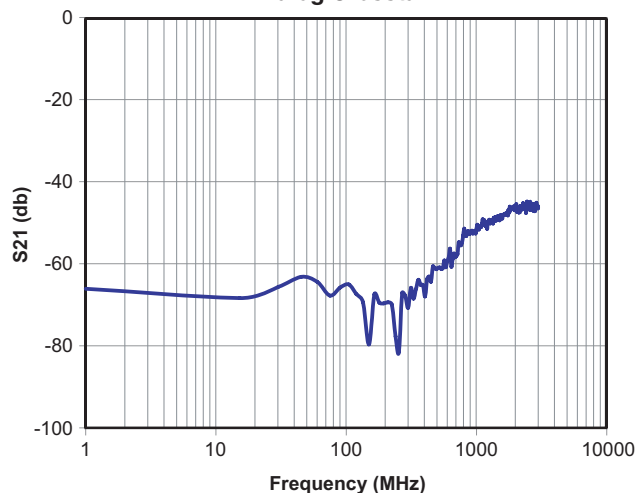
3. The working peak reverse voltage, V_{RWM}, should be equal to or greater than the DC or continuous peak operating voltage level.
4. V_{BR} is measured at the pulse test current I_T.
5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.
6. Total capacitance is equal to 2 x C_{CH}.
7. Measured at 25°C, V_R = 2.5V, f = 1.0MHz.
8. Guaranteed by design.

Typical Performance Characteristics

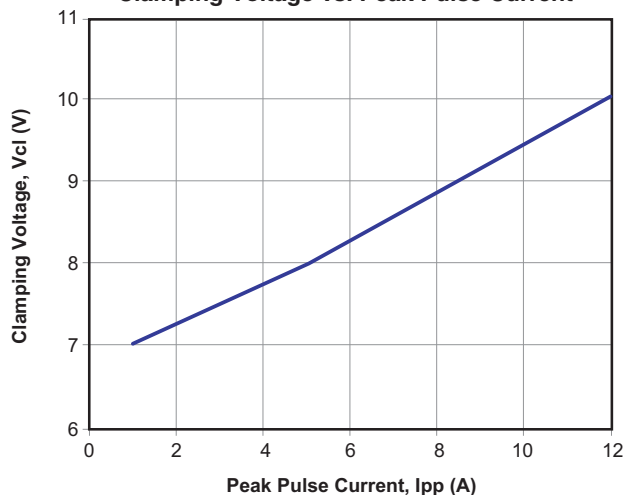
Insertion Loss Characteristics



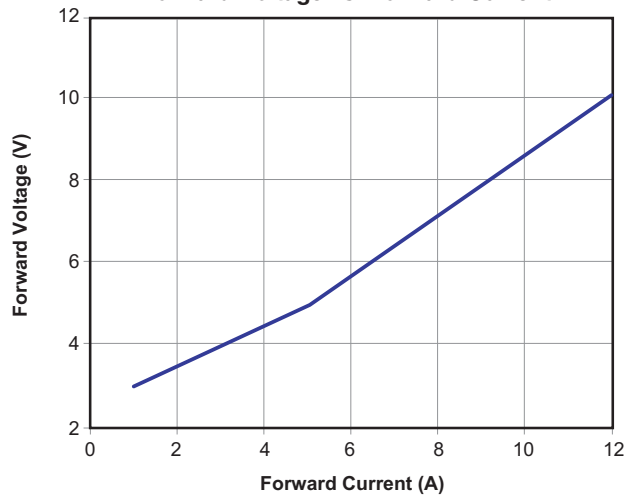
Analog Crosstalk



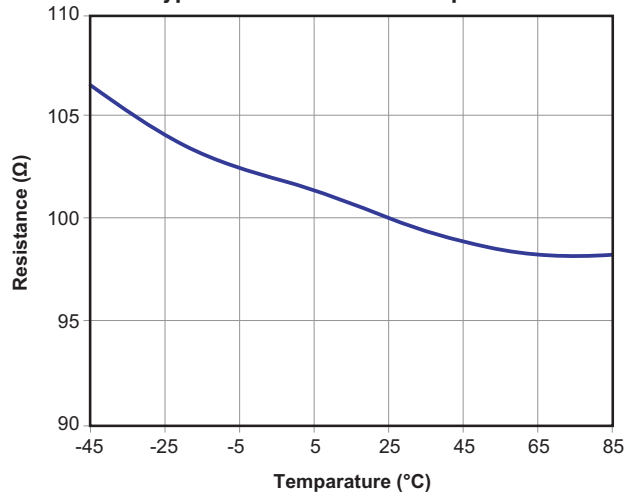
Clamping Voltage vs. Peak Pulse Current



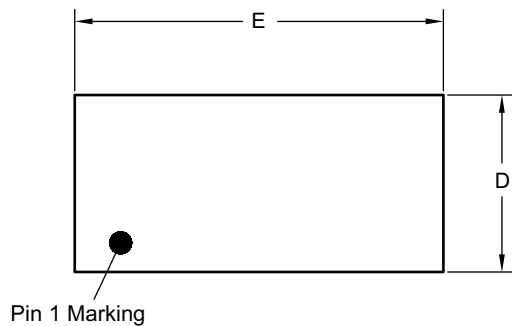
Forward Voltage vs. Forward Current



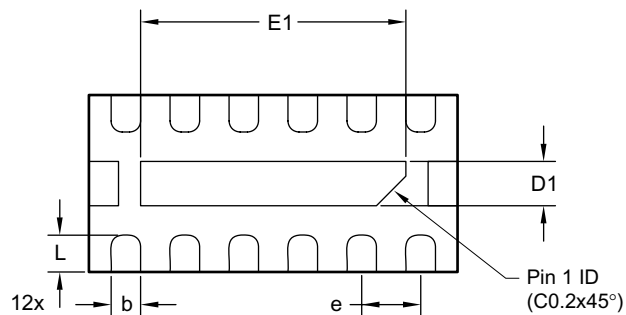
Typical Resistance vs. Temperature



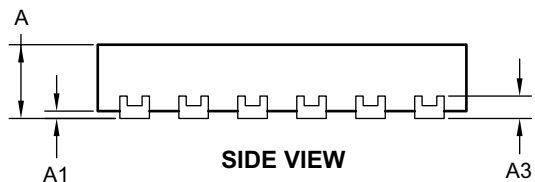
Package Dimensions, DFN 2.5 x 1.2, 12L EP1 S



TOP VIEW

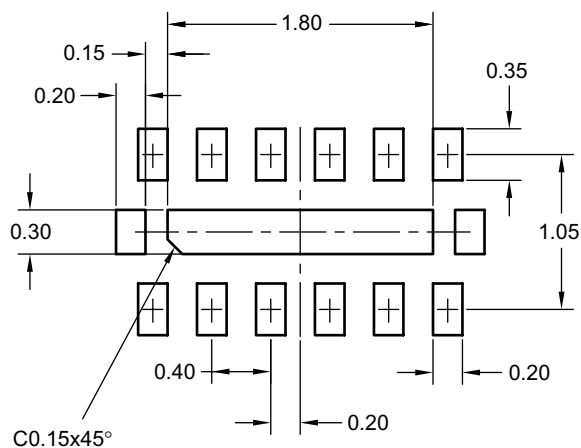


BOTTOM VIEW



SIDE VIEW

RECOMMENDED LAND PATTERN



UNIT: mm

Dimensions in millimeters

Symbols	Min.	Nom.	Max.
A	0.50	0.55	0.60
A1	0.00	—	0.05
b	0.15	0.20	0.25
A3	0.152 REF		
D	1.15	1.20	1.25
E	2.45	2.50	2.55
D1	0.25	0.30	0.35
D1	1.75	1.80	1.85
e	0.40 BSC		
L	0.20	0.24	0.30

Dimensions in inches

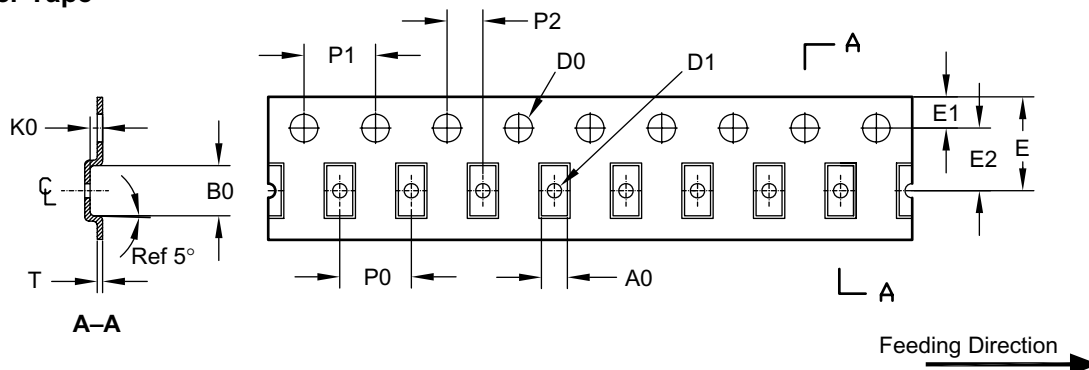
Symbols	Min.	Nom.	Max.
A	0.020	0.022	0.024
A1	0.000	—	0.002
b	0.006	0.008	0.010
A3	0.006 REF		
D	0.045	0.047	0.049
E	0.096	0.098	0.100
D1	0.010	0.012	0.014
D1	0.069	0.071	0.073
e	0.016 BSC		
L	0.008	0.010	0.012

Notes:

1. All dimensions are in millimeters. Converted inch dimensions are not necessarily exact.

Tape and Dimensions, DFN 2.5 x 1.2

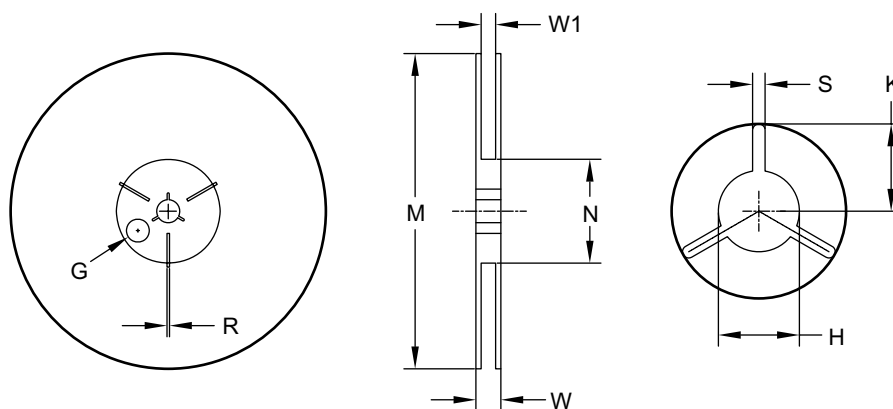
Carrier Tape



UNIT: mm

Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
DFN 2.5x1.2	1.45 ±0.05	2.80 ±0.05	0.70 ±0.05	ø1.55 ±0.05	ø0.80 ±0.05	8.00 ±0.03	1.75 ±0.1	3.50 ±0.05	4.00 ±0.10	4.0 ±0.10	2.0 ±0.05	0.30 ±0.05

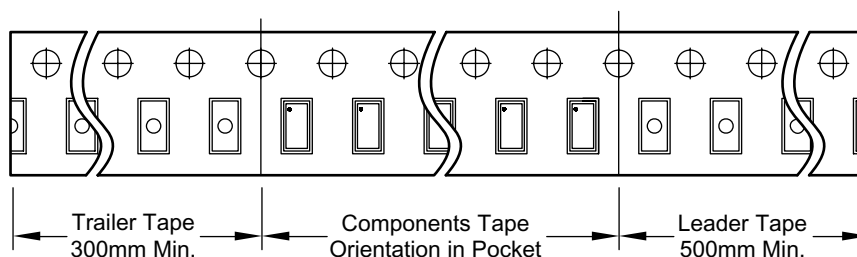
Reel



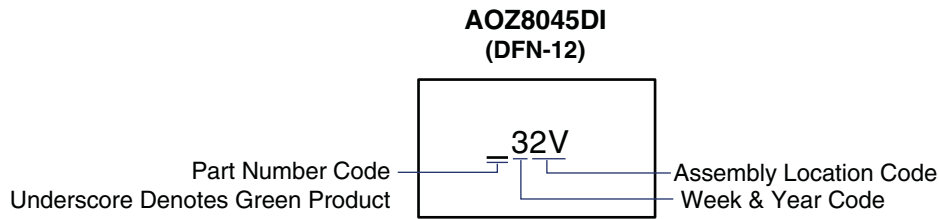
UNIT: mm

Tape Size	Reel Size	M	N	W	W1	H	S	K	E
8mm	ø178	ø178.0 ±1.0	ø60.0 ±0.5	11.80 ±0.5	9.0 ±0.5	ø13.0 +0.5 / -0.2	2.40 ±0.1	10.25 ±0.2	ø9.8

Leader / Trailer & Orientation



Package Marking



This data sheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.